











SN74LV08A

SCLS387M-SEPTEMBER 1997-REVISED OCTOBER 2014

SN74LV08A Quadruple 2-Input Positive-AND Gates

Features

- 2-V to 5.5-V V_{CC} Operation
- Max t_{pd} of 7 ns at 5 V
- Typical V_{OLP} (Output Ground Bounce) $< 0.8 \text{ V at V}_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Typical V_{OHV} (Output V_{OH} Undershoot) $> 2.3 \text{ V at V}_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Support Mixed-Mode Voltage Operation on All Ports
- Ioff Supports Live Insertion, Partial-Power-Down Mode, and Back-Drive Protection
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model
 - 200-V Machine Model
 - 1000-V Charged-Device Model

2 Applications

- Servers
- Telecom Infrastructure
- PCs and Notebooks
- TV Set-Top Boxes

3 Description

This quadruple 2-input positive-AND gate is designed for 2-V to 5.5-V V_{CC} operation. The SN74LV08A the Boolean performs function $Y = A \cdot B$ or $Y = \overline{A + B}$ in positive logic.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
	TVSOP (14)	3.60 mm × 4.40 mm		
	SOIC (14)	8.65 mm × 3.91 mm		
SN74LV08A	VQFN (14)	3.50 mm× 3.50 mm		
	SSOP (14)	6.20 mm × 5.30 mm		
	TSSOP (14)	5.00 mm × 4.40 mm		

⁽¹⁾ For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic

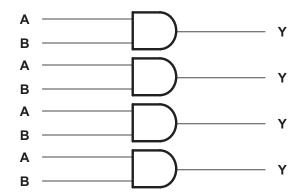




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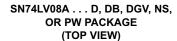
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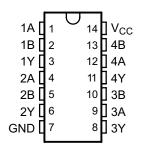
5 Revision History

CI	hanges from Revision L (October 2010) to Revision M	Page
	Updated document to new TI data sheet format	
•	Deleted Ordering Information table.	1
•	Deleted SN54LV08A device from data sheet	1
•	Added Applications.	1
•	Added Pin Functions table	3
•	Added Handling Ratings table	4
•	Changed MAX operating temperature to 125°C in Recommended Operating Conditions table	5
•	Added Thermal Information table.	5
•	Added Typical Characteristics	7
•	Added Detailed Description section	9
•	Added Application and Implementation section	10
•	Added Power Supply Recommendations and Layout sections	11

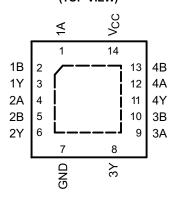


6 Pin Configuration and Functions





SN74LV08A . . . RGY PACKAGE (TOP VIEW)



Pin Functions

	PIN						
	SN74LV08A	I/O	DESCRIPTION				
NAME	D, DB, DGV, NS, PW, RGY						
1A	1	I	1A Input				
1B	2	1	1B Input				
1Y	3	0	1Y Output				
2A	4	I	2A Input				
2B	5	I	2B Input				
2Y	6	0	2Y Output				
3Y	8	0	3Y Output				
3A	9	1	3A Input				
3B	10	I	3B Input				
4Y	11	0	4Y Output				
4A	12	I	4A Input				
4B	13	1	4B Input				
GND	7	_	Ground Pin				
V _{CC}	14	_	Power Pin				

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7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	7	٧
VI	Input voltage range ⁽²⁾		-0.5	7	V
Vo	Voltage range applied to any output i	oltage range applied to any output in the high-impedance or power-off state (2)			
Vo	Output voltage range (2)(3)	Output voltage range ⁽²⁾⁽³⁾			
I _{IK}	Input clamp current	V _I < 0		-20	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current $V_O = 0$ to V_{CC}			±25	mA
	Continuous current through V _{CC} or G	Continuous current through V _{CC} or GND			

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 Handling Ratings

			MIN	MAX	UNIT
T _{stg}	Storage temperature rang	ie e	- 65	150	°C
V _(ESD)	Floatroctatio discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	0	2000	V
	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	0	1000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

²⁾ The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ This value is limited to 5.5 V maximum.



7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted) (1)

			SN74LV	A80			
			MIN	MAX	UNIT		
V _{CC}	Supply voltage		2	5.5	V		
		V _{CC} = 2 V	1.5				
.,		V _{CC} = 2.3 V to 2.7 V	V _{CC} × 0.7		.,		
V _{IH}	High-level input voltage	V _{CC} = 3 V to 3.6 V	V _{CC} × 0.7		V		
		V _{CC} = 4.5 V to 5.5 V	V _{CC} × 0.7				
		V _{CC} = 2 V		0.5			
. ,		V _{CC} = 2.3 V to 2.7 V		V _{CC} × 0.3	V		
V_{IL}	Low-level input voltage	V _{CC} = 3 V to 3.6 V		$V_{CC} \times 0.3$	V		
		V _{CC} = 4.5 V to 5.5 V		V _{CC} × 0.3 5			
VI	Input voltage		0	5.5	V		
Vo	Output voltage		0	V _{CC}	V		
-0		V _{CC} = 2 V		-50	μΑ		
	LP-da land and a compart	V _{CC} = 2.3 V to 2.7 V		-2			
Іон	High-level output current	V _{CC} = 3 V to 3.6 V		-6	mA		
		V _{CC} = 4.5 V to 5.5 V		-12			
		V _{CC} = 2 V		50	μΑ		
	Lavelanal andrews andrews	V _{CC} = 2.3 V to 2.7 V		2			
l _{OL}	Low-level output current	V _{CC} = 3 V to 3.6 V		6	mA		
		V _{CC} = 4.5 V to 5.5 V		12			
		V _{CC} = 2.3 V to 2.7 V		200			
Δt/Δv	\text{\lambda}\transition rise and fall rate	V _{CC} = 3 V to 3.6 V		100	ns/V		
		V _{CC} = 4.5 V to 5.5 V		20			
T _A	Operating free-air temperature		-40	125	°C		

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs* (SCBA004).

7.4 Thermal Information

					SN74LV08A				
	THERMAL METRIC(1)	D	DB	DGV	N	NS	PW	RGY	UNIT
		14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	90.6	107.1	129.0	57.4	90.7	122.6	57.5	
R _{0JC(top)}	Junction-to-case (top) thermal resistance	50.9	59.6	52.1	44.9	48.3	51.4	70.8	
R _{eJB}	Junction-to-board thermal resistance	44.8	54.4	62.0	37.2	49.4	64.4	33.6	°C/W
ΨЈТ	Junction-to-top characterization parameter	14.7	20.5	6.5	30.1	14.6	6.7	3.4	*C/VV
ΨЈВ	Junction-to-board characterization parameter	44.5	53.8	61.3	37.1	49.1	63.8	33.7	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	_	-	-	-	-	-	13.9	

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

Product Folder Links: SN74LV08A



7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{cc}		LV08A to 85°C		LV08A o 125°C	UNIT
			MIN	TYP MAX	MIN	TYP MAX	
	$I_{OH} = -50 \mu A$	2 V to 5.5 V	$V_{CC} - 0.1$		$V_{CC} - 0.1$		
V	$I_{OH} = -2 \text{ mA}$	2.3 V	2		2		v
V _{OH}	$I_{OH} = -6 \text{ mA}$	3 V	2.48		2.48		V
	I _{OH} = -12 mA	4.5 V	3.8		3.8		
	I _{OL} = 50 μA	2 V to 5.5 V		0.1		0.1	
V	I _{OL} = 2 mA	2.3 V		0.4		0.4	v
V _{OL}	I _{OL} = 6 mA	3 V		0.44		0.44	
	I _{OL} = 12 mA	4.5 V		0.55		0.55	
I _I	V _I = 5.5 V or GND	0 to 5.5 V		±1		±1	μΑ
I _{CC}	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V		20		20	μΑ
I _{off}	V_I or $V_O = 0$ to 5.5 V	0		5		5	μΑ
C	V V or CND	3.3 V		3.3		3.3	nE.
C _i	$V_I = V_{CC}$ or GND	5 V	·	3.3	·	3.3	pF

7.6 Switching Characteristics, $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T,	_A = 25°C		SN74L	V08A	_	LV08A o 125°C	UNIT
		(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A or D	V	C _L = 15 pF		7.9 ⁽¹⁾	13.8 ⁽¹⁾	1	16	1	17	
	AOIB	A or B Y	C _L = 50 pF		10.5	17.3	1	20	1	21	ns

⁽¹⁾ On products compliant to MIL-PRF-38535, this parameter is not production tested.

7.7 Switching Characteristics, V_{CC} = 3.3 V ± 0.3 V

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

	PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD	T,	_A = 25°C		SN74L	/08A	SN74L\ -40°C to		UNIT	
			(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX		
		4 5	A or B Y	C _L = 15 pF		5.6 ⁽¹⁾	8.8(1)	1	10.5	1	11.5		
	T _{pd}	AUIB		C _L = 50 pF		7.5	12.3	1	14	1	15	ns	

⁽¹⁾ On products compliant to MIL-PRF-38535, this parameter is not production tested.

7.8 Switching Characteristics, $V_{CC} = 5 V \pm 0.5 V$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)			T _A = 25°C			A80V	SN74LV08A -40°C to 125°C		UNIT
	(INPUT)	(001701)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
	A or D	V	C _L = 15 pF		4.1 ⁽¹⁾	5.9 ⁽¹⁾	1	7	1	8	
^T pd	A or B	Y	C _L = 50 pF		5.5	7.9	1	9	1	10	ns

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.



7.9 Noise Characteristics(1)

 $V_{CC} = 3.3 \text{ V}, C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}$

	PARAMETER	SN	LINUT		
	PARAMETER	MIN	TYP	MAX	UNIT
$V_{OL(P)}$	Quiet output, maximum dynamic V _{OL}		0.2	8.0	V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.1	-0.8	V
$V_{OH(V)}$	Quiet output, minimum dynamic V _{OH}		3.1		V
$V_{IH(D)}$	High-level dynamic input voltage	2.31			V
$V_{IL(D)}$	Low-level dynamic input voltage			0.99	V

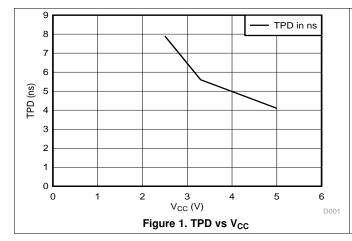
⁽¹⁾ Characteristics are for surface-mount packages only.

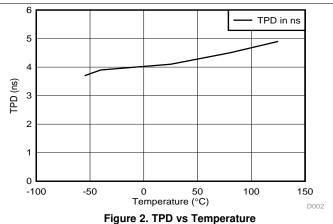
7.10 Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V _{CC}	TYP	UNIT
,	C Dower discinction conscitance	C F0 ~F	3.3 V	8	
	C _{pd} Power dissipation capacitance	$C_L = 50 \text{ pF}, \qquad f = 10 \text{ MHz}$	5 V	10	p⊦

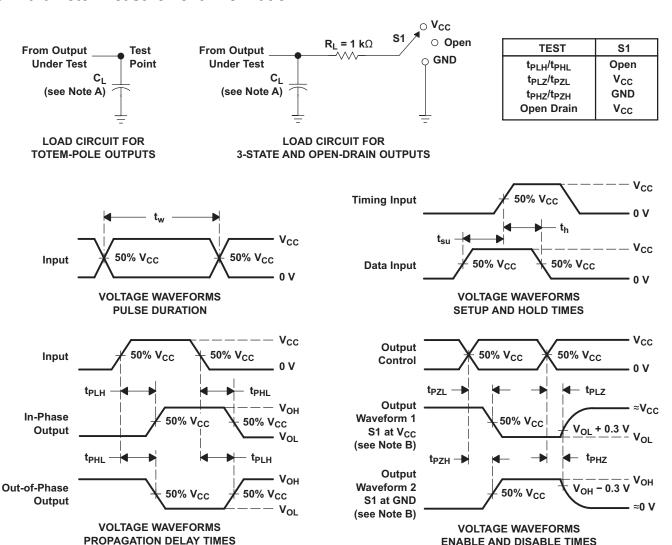
7.11 Typical Characteristics







Parameter Measurement Information



C_L includes probe and jig capacitance.

INVERTING AND NONINVERTING OUTPUTS

- Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output
 - Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output
- All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \ \Omega$, $t_r \leq$ 3 ns, C.
- D. The outputs are measured one at a time, with one input transition per measurement.
- t_{PLZ} and t_{PHZ} are the same as t_{dis}.
- F. tPZL and tPZH are the same as ten.
- G. t_{PHL} and t_{PLH} are the same as t_{pd}.
- All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms

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ENABLE AND DISABLE TIMES

LOW- AND HIGH-LEVEL ENABLING



9 Detailed Description

9.1 Overview

This quadruple 2-input positive-AND gate is designed for 2-V to 5.5-V V_{CC} operation. The SN74LA08A device performs the Boolean function $Y = A \cdot B$ or $Y = \overline{A + B}$ in positive logic.

This device is fully specified for partial-power-down application using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down.

9.2 Functional Block Diagram



Figure 4. Logic Diagram, Each Gate (Positive Logic)

9.3 Feature Description

- · Wide operating voltage range
 - Operates From 2 V to 5.5 V
- Allows down voltage translation
 - Inputs accept voltages to 5.5 V
- I_{off} feature
 - Allows voltages on the input or output when V_{CC} is 0 V

9.4 Device Functional Modes

Table 1. Function Table (Each Gate)

INP	OUTPUT					
Α	A B					
Н	Н	Н				
L	Χ	L				
X	L	L				

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10 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

The SN74LV08A is a low-drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The inputs can accept voltages up to 5.5~V at any valid V_{CC} , thus making it ideal for down translation.

10.2 Typical Application

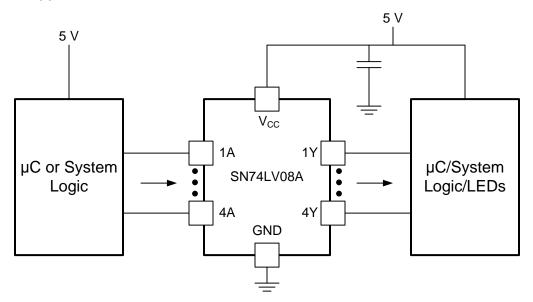


Figure 5. Application Diagram

10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

10.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions:
 - For specified high and low levels, see V_{IH} and V_{IL} in Recommended Operating Conditions table.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC}.
- 2. Recommend Output Conditions:
 - Load currents should not exceed 25 mA per output and 50 mA total for the part.
 - Outputs should not be pulled above V_{CC}.

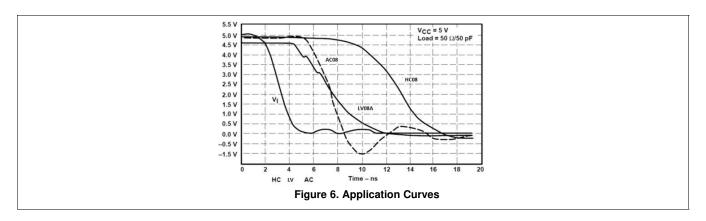
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Typical Application (continued)

10.2.3 Application Curves



11 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions* table.

Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1 μ F capacitor is recommended. If there are multiple V_{CC} terminals then 0.01 μ F or 0.022 μ F capacitors are recommended for each power terminal. It is ok to parallel multiple bypass capacitors to reject different frequencies of noise. 0.1 μ F and 1.0 μ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for the best results.

12 Layout

12.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in Figure 7 are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} , whichever makes more sense or is more convenient. It is acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the I/Os so they also cannot float when disabled.

12.2 Layout Example

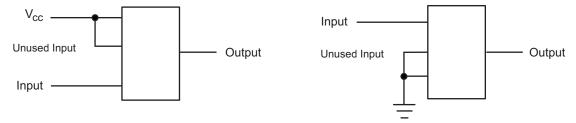


Figure 7. Layout Diagram

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13 Device and Documentation Support

13.1 Trademarks

All trademarks are the property of their respective owners.

13.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN74LV08ADBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08ADGVR	ACTIVE	TVSOP	DGV	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08ADR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08ANSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	74LV08A	Samples
SN74LV08APWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08APWRE4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08APWRG3	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08APWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV08A	Samples
SN74LV08ARGYR	ACTIVE	VQFN	RGY	14	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	LV08A	Samples
SN74LV08ARGYRG4	ACTIVE	VQFN	RGY	14	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	LV08A	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: Til defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

PACKAGE OPTION ADDENDUM

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(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74LV08A:

Automotive: SN74LV08A-Q1

● Enhanced Product : SN74LV08A-EP

NOTE: Qualified Version Definitions:

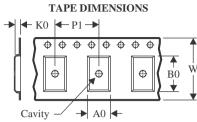
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications



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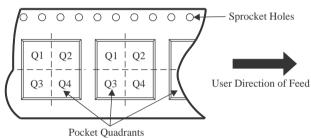
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

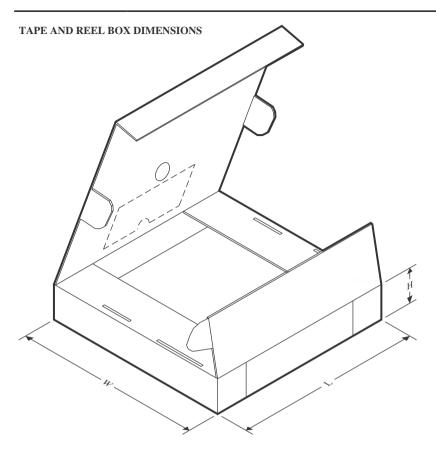


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV08ADBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74LV08ADGVR	TVSOP	DGV	14	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
SN74LV08ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LV08ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LV08ANSR	so	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74LV08APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV08APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV08APWRG3	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV08APWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV08ARGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1

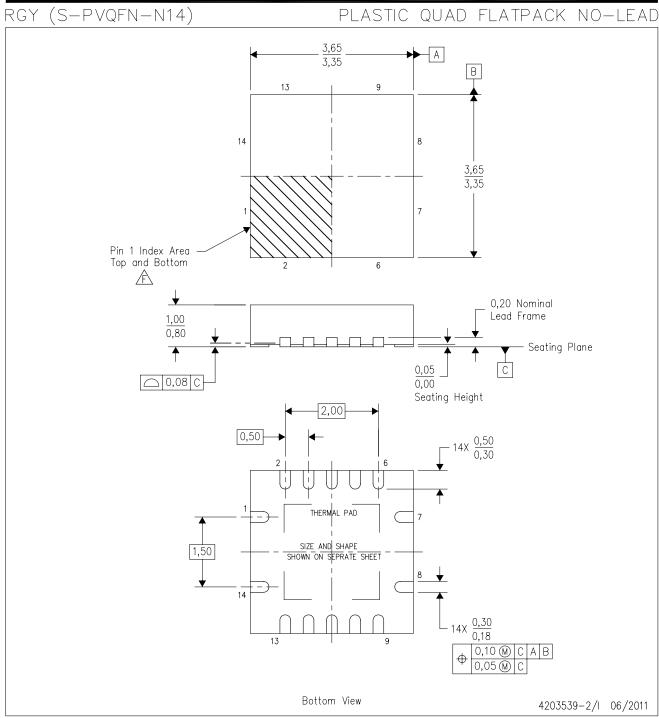


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*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV08ADBR	SSOP	DB	14	2000	356.0	356.0	35.0
SN74LV08ADGVR	TVSOP	DGV	14	2000	356.0	356.0	35.0
SN74LV08ADR	SOIC	D	14	2500	356.0	356.0	35.0
SN74LV08ADR	SOIC	D	14	2500	356.0	356.0	35.0
SN74LV08ANSR	so	NS	14	2000	356.0	356.0	35.0
SN74LV08APWR	TSSOP	PW	14	2000	364.0	364.0	27.0
SN74LV08APWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LV08APWRG3	TSSOP	PW	14	2000	364.0	364.0	27.0
SN74LV08APWRG4	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LV08ARGYR	VQFN	RGY	14	3000	356.0	356.0	35.0



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



RGY (S-PVQFN-N14)

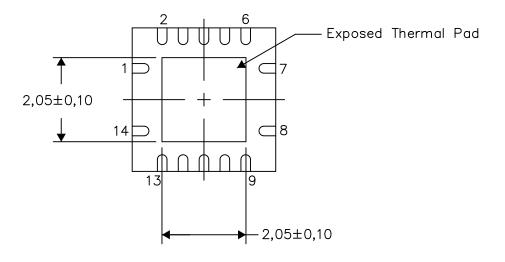
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

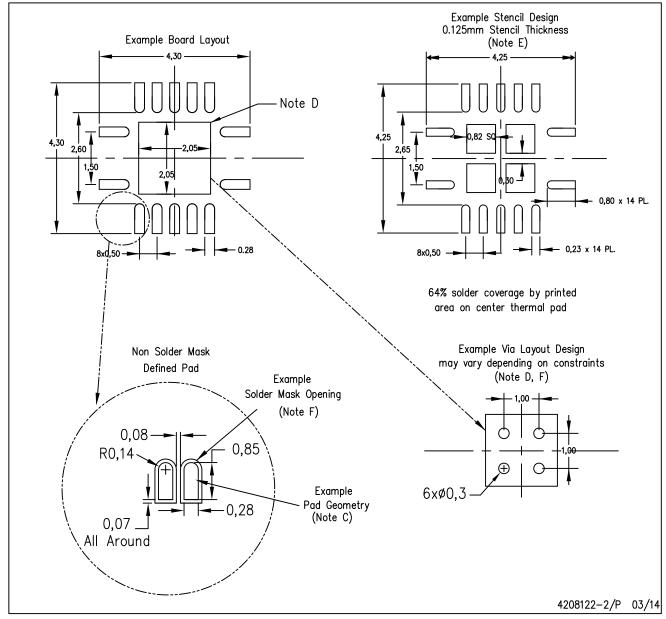
4206353-2/P 03/14

NOTE: All linear dimensions are in millimeters



RGY (S-PVQFN-N14)

PLASTIC QUAD FLATPACK NO-LEAD



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout.

 These documents are available at www.ti.com www.ti.com>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

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